## NSN 5961-00-022-5675

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View Online at https://aerobasegroup.com/nsn/5961-00-022-5675 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -90.0 collector to base voltage, dc and -65.0 collector-to-emitter, substaining voltage, base open-circuited and -7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -1.00 amperes source cutoff current and -0.50 amperes source cutoff current **Power Rating Per Characteristic:** 7.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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